

°C/W

°C/W

NDT3055L Rev.A1

42

12

 $R_{\theta JC}$

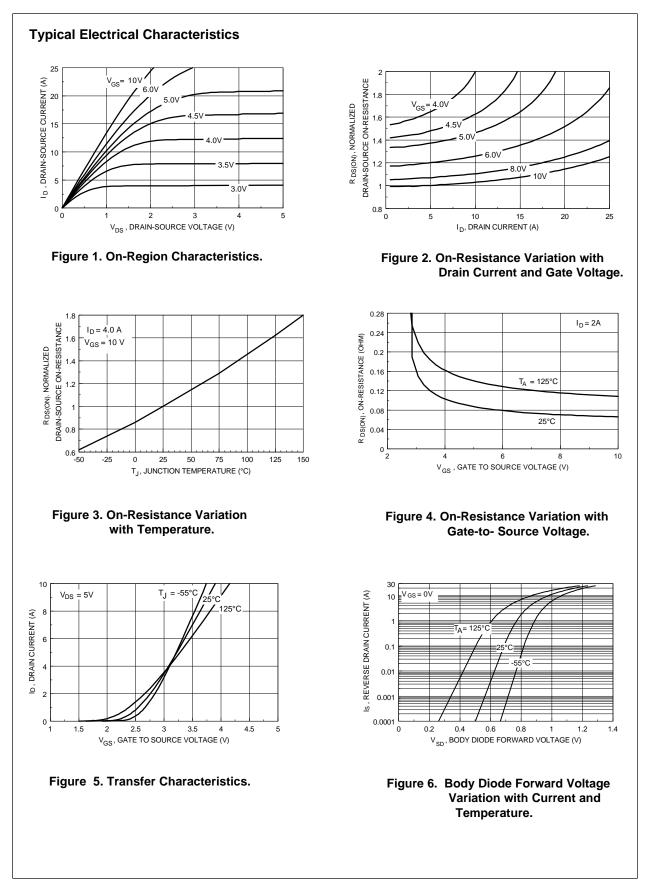
Thermal Resistance, Junction-to-Ambient (Note 1a)

(Note 1)

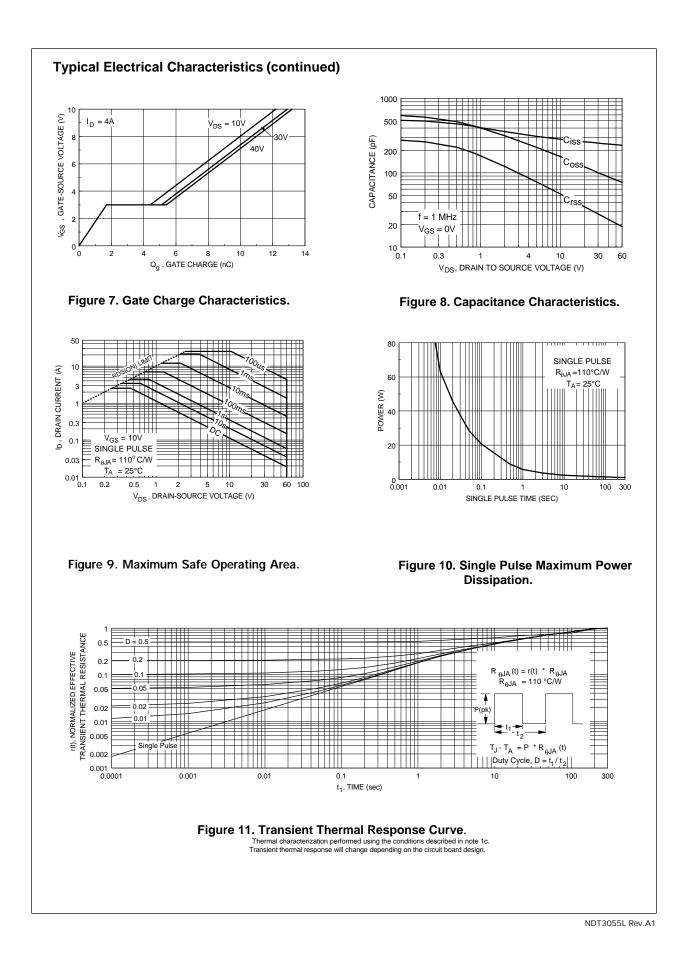
Thermal Resistance, Junction-to-Case

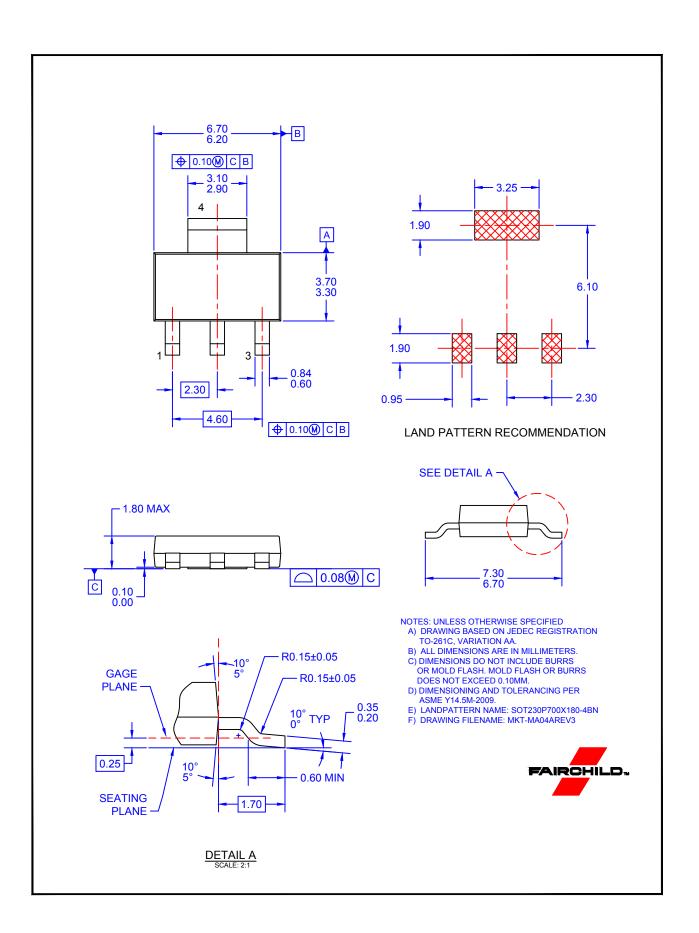
* Order option J23Z for cropped center drain lead.

V mV/°C 1 μA 50 μA 00 nA 00 nA	Typ Max 55 1 55 1 50 100 -100 100	Min Typ 60 55		Conditions		Symbol
mV/ ^ρ C 1 μA 50 μA 00 nA 2 V	1 50 100				RACTERISTICS	OFF CHAR/
1 μA 50 μA 00 nA 00 nA 2 V	1 50 100	55	to 25 °C	$V_{GS} = 0 V, I_{D} = 250 \mu A$	Drain-Source Breakdown Voltage	BV _{DSS}
1 μA 50 μA 00 nA 00 nA 2 V	50 100			$I_{\rm D}$ = 250 µA, Referenced to	Breakdown Voltage Temp. Coefficient	$\Delta BV_{DSS}/\Delta T_{J}$
50 μA 00 nA 00 nA 2 V	50 100			$V_{DS} = 60 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$	Zero Gate Voltage Drain Current	DSS
00 nA 00 nA 2 V	100		T_=125°C	DS CC , GS C		DSS
00 nA 2 V			- ,	$V_{GS} = 20 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$	Gate - Body Leakage, Forward	GSSF
2 V				$V_{GS} = -20 \text{ V}, V_{DS} = 0 \text{ V}$	Gate - Body Leakage, Reverse	GSSF
				63 - 7 53 -	ACTERISTICS (Note 2)	
	1.6 2	1 1.6		$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	Gate Threshold Voltage	V _{GS(th)}
	-4		to 25 °C	$I_p = 250 \mu\text{A}$, Referenced to	Gate Threshold Voltage Temp. Coefficient	$\Delta V_{GS(th)} / \Delta T_J$
	0.07 0.1	0.07		$V_{GS} = 10 \text{ V}, I_D = 4 \text{ A}$	Static Drain-Source On-Resistance	R _{DS(ON)}
		0.125	T_=125°C	$V_{GS} = 10$ V, $V_D = 17$		[•] DS(ON)
		0.123	1,1200	$V_{GS} = 4.5 \text{ V}, I_{D} = 3.7 \text{ A}$		
A	0.12	10		$V_{GS} = 5, V_{DS} = 10 V$	On-State Drain Current	 I
S	7	-		$V_{\rm DS} = 5 \text{ V}, \ I_{\rm D} = 4 \text{ A}$	Forward Transconductance	g _{FS}
				$v_{DS} = o v, v_D = v_{TT}$	CHARACTERISTICS	
pF	345	345		$V_{-1} = 25$, $V_{-1} = 0$ V	Input Capacitance	C _{iss}
pF	110			$V_{\rm DS} = 25, V_{\rm GS} = 0 V,$ f = 1.0 MHz	Output Capacitance	C _{oss}
pF	30				Reverse Transfer Capacitance	C _{rss}
					G CHARACTERISTICS (Note 2)	
20 ns	5 20	5		$V_{DD} = 25, I_{D} = 1 A,$	Turn - On Delay Time	D(on)
20 ns	7.5 20	7.5		$V_{\rm GS} = 10$ V, $R_{\rm GEN} = 6$ Ω	Turn - On Rise Time	r
50 ns	20 50	20			Turn - Off Delay Time	t _{D(off)}
20 ns	7 20	7			Turn - Off Fall Time	
20 nC	13 20	13		$V_{DS} = 40 \text{ V}, I_{D} = 4 \text{ A},$	Total Gate Charge	
nC	1.7	1.7		$V_{GS} = 10 V$	Gate-Source Charge	8
nC	3.2	3.2			Gate-Drain Charge	
1	1			MUM RATINGS	URCE DIODE CHARACTERISTICS AND MAX	·
2.5 A	2.5			ward Current	Maximum Continuous Drain-Source Diode Fo	s
.2 V	0.8 1.2	0.8	ote 2)	$V_{GS} = 0 V, I_{S} = 2.5 A$ (Note	Drain-Source Diode Forward Voltage	V _{SD}
20	13 20 1.7	13 1.7 3.2		MUM RATINGS ward Current $V_{GS} = 0 \text{ V}, \text{ I}_{S} = 2.5 \text{ A}$ (Note	Total Gate Charge Gate-Source Charge Gate-Drain Charge JRCE DIODE CHARACTERISTICS AND MAX Maximum Continuous Drain-Source Diode Formation	t _f Q _g Q _{gg} DRAIN-SOUI I _S V _{SD} Notes: 1. R _{p,A} is the sum



NDT3055L Rev.A1







* Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. TO OBTAIN THE LATEST, MOST UP-TO-DATE DATASHEET AND PRODUCT INFORMATION, VISIT OUR WEBSITE AT <u>HTTP://WWW.FAIRCHILDSEMI.COM</u>, FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

AUTHORIZED USE

Unless otherwise specified in this data sheet, this product is a standard commercial product and is not intended for use in applications that require extraordinary levels of quality and reliability. This product may not be used in the following applications, unless specifically approved in writing by a Fairchild officer: (1) automotive or other transportation, (2) military/aerospace, (3) any safety critical application – including life critical medical equipment – where the failure of the Fairchild product reasonably would be expected to result in personal injury, death or property damage. Customer's use of this product is subject to agreement of this Authorized Use policy. In the event of an unauthorized use of Fairchild's product, Fairchild accepts no liability in the event of product failure. In other respects, this product shall be subject to Fairchild's Worldwide Terms and Conditions of Sale, unless a separate agreement has been signed by both Parties.

ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.fairchildsemi.com, under Terms of Use

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufacturers of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed applications, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handling and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address any warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

PRODUCT STATUS DEFINITIONS

Definition of Terms					
Datasheet Identification	Product Status	Definition			
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.			
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.			
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.			
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.			

Rev. 177

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Fairchild Semiconductor: